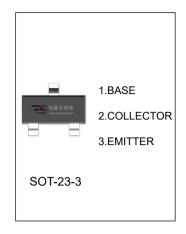


A1015 TRANSI STOR (PNP)

FEATURES

- High voltage and high current
- Excellent h_{FE} Linearity
- Complementary to C1815



MAXIMUM RATINGS (Ta=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit	
V _{CBO}	Collector-Base Voltage	-50 V		
V _{CEO}	Collector-Emitter Voltage	-50	V	
V _{EBO}	Emitter-Base Voltage	-5	V	
Ic	Collector Current -Continuous	-150	mA	
Pc	Collector Power Dissipation	200	mW	
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	625 °C/W		
T _J ,T _{stg}	Junction Temperature	-55~+150	℃	

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C = -100u A,I _E =0				V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C = -0.1mA, I _B =0 -5				V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E = -100 u A, I _C =0 -5				V
Collector cut-off current	I _{CBO}	V _{CB} =-50V ,I _E =0			-0.1	μA
Collector cut-off current	I _{CEO}	V _{CE} = -50V , I _B =0			-1	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} =-5V, I _C =0			-0.1	μΑ
DC current gain	h _{FE}	V _{CE} = 6V,I _C = -2mA 120			400	
Collector-emitter saturation voltage	V _{CE} (sat)	I _C =-100 mA, I _B = -10mA		-0.3	V	
Base-emitter saturation voltage	V _{BE} (sat)	I _C =-100 mA, I _B = -10mA		-1.1	V	
Transition frequency	f _T	V _{CE} =-10V,I _C = -1mA f=30MHz			MHz	

CLASSIFICATION OF hFE

Rank	L	Н
Range	120-240	200-400



